NSN 5962-01-363-6479

Memory Microcircuit - Page 1 of 1



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Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Milstar
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Criticality Code Justification:
Feat
Case Outline Source And Designator:
D-3 mil-m-38510
Terminal Surface Treatment:
Tin
Product Name:
Mckt, memory digital, cmos 16k (2048 x 8) bit static ram, monolithic silicon
Voltage Rating And Type Per Characteristic:
4.5 volts total supply and 4.5 volts total supply
Memory Device Type:
Ram
Special Features: Esd; hci. Selected from p/n 34371 hs1-65c162rrh-8
Terminal Type And Quantity:
24 beam lead
Shelf Life:
N/a
unit Of Measure:
Unit Of Measure:
 Demilitarization:

No Eiia
Fiig:
A458a0